

V <sub>DSS</sub>	600V
R <sub>DS(on)</sub> (Max.)	0.196Ω
Ι <sub>D</sub>	±20A
P <sub>D</sub>	120W

## Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V<sub>GSS</sub>) guaranteed to be ±20V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating ; RoHS compliant

# Application

Switching

# • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

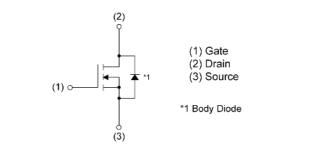
Parameter		Symbol	Value	Unit
Drain - Source voltage		V <sub>DSS</sub>	600	V
Continuous droin ourrent	T <sub>C</sub> = 25°C	۱ <sub>D</sub> *1	±20	А
Continuous drain current	T <sub>C</sub> = 100°C	۱ <sub>D</sub> *1	±9.4	А
Pulsed drain current	I <sub>DP</sub> *2	±60	А	
Gate - Source voltage	static	V <sub>GSS</sub>	±20	V
	AC(f>1Hz)		±30	V
Avalanche current, repetitive		I <sub>AR</sub>	3.4	А
Avalanche energy, single pulse		$E_{AS}^{*3}$	418	mJ
Avalanche energy, repetitive		$E_{AR}^{*3}$	0.63	mJ
Power dissipation ( $T_C = 25^{\circ}C$ )	P <sub>D</sub> *4	120	W	
Junction temperature	Tj	150	°C	
Operating junction and storage te	T <sub>stg</sub>	-55~+150	°C	

# ●Outline





### Inner circuit



# Packaging specifications

Туре	Packing	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Quantity (pcs)	300
	Taping code	C17
	Marking	R6020ENZ

# ● Absolute maximum ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values	Unit
Reverse diode dv/dt	dv/dt	-	15	V/ns
Drain - Source voltage slope	dv/dt	V <sub>DS</sub> = 480V, T <sub>j</sub> = 25°C	50	V/ns

### •Thermal resistance

Peremeter	Sumbol	Values			Lipit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub>	-	-	1.04	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	40	°C/W
Soldering temperature, wavesoldering for 10s	$T_{sold}$	-	-	265	°C

# •Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol Conditions -		Values			Unit
Parameter	Зупрог	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		600	-	-	V
		V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V				
Zero gate voltage drain current	I <sub>DSS</sub>	T <sub>j</sub> = 25°C	-	-	100	μA
		T <sub>j</sub> = 125°C	-	-	1000	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	-	-	±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	2.0	-	4.0	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 9.5A				
Static drain - source on - state resistance	${\sf R}_{\sf DS(on)}^{*5}$	T <sub>j</sub> = 25°C	-	0.170	0.196	Ω
		T <sub>j</sub> = 125°C	-	0.360	-	
Gate resistance	R <sub>G</sub>	f =1MHz, open drain	-	5.8	-	Ω



# •Electrical characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Sumphal	Conditions		Values			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Transfer Admittance	Y <sub>fs</sub>  ⁵⁵	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10A	5	10	-	S	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	1400	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	1200	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	130	-		
Effective output capacitance, energy related	C <sub>o(er)</sub>	V <sub>GS</sub> = 0V	-	56	-	- 5	
Effective output capacitance, time related	C <sub>o(tr)</sub>	V <sub>DS</sub> = 0V to 480V	-	266	-	рF	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 480 \text{V}, \text{V}_{GS} = 10 \text{V}$	-	35	-		
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 10A	-	53	-		
Turn - off delay time	t <sub>d(off)</sub> *5	R <sub>L</sub> ≃ 47.5Ω	-	150	-	ns	
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	67	-		

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Parameter	Symbol Conditions	Conditions	Values			1.1.0.16
		Min.	Тур.	Max.	Unit	
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≃ 480V,	-	60	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 20A,	-	8	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	33	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> = 480V, I <sub>D</sub> = 20A	-	6.9	-	V

\*1 Limited only by maximum channel temperature allowed.

\*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

\*3 L $\doteqdot$ 70mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>j</sub>=25°C

\*4 T<sub>C</sub>=25°C

\*5 Pulsed

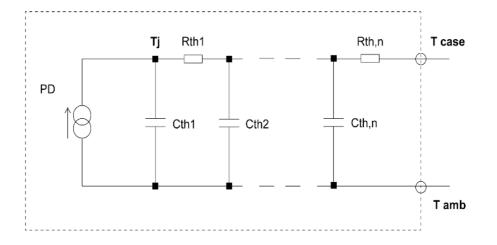


# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

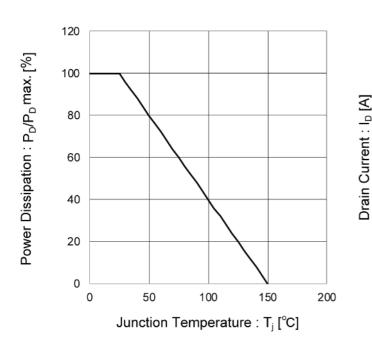
Parameter	Symbol Conditions		Values			Unit
	Зупрог	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	ا <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	-	20	A
Pulse forward current	۱ <sub>SP</sub> *2	T <sub>c</sub> - 25 C	-	-	60	А
Forward voltage	$V_{SD}^{*5}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *5		-	550	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	I <sub>S</sub> = 20A, V <sub>GS</sub> =0V di/dt = 100A/µs	-	10.4	-	μC
Peak reverse recovery current	۱ <sub>mm</sub> *5		-	38	-	А

## •Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	0.129		C <sub>th1</sub>	0.00475	
R <sub>th2</sub>	0.627	K/W	C <sub>th2</sub>	0.0387	Ws/K
R <sub>th3</sub>	1.22		C <sub>th3</sub>	1.06	







# Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

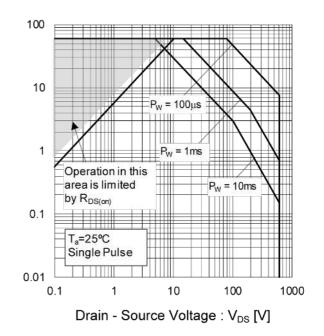
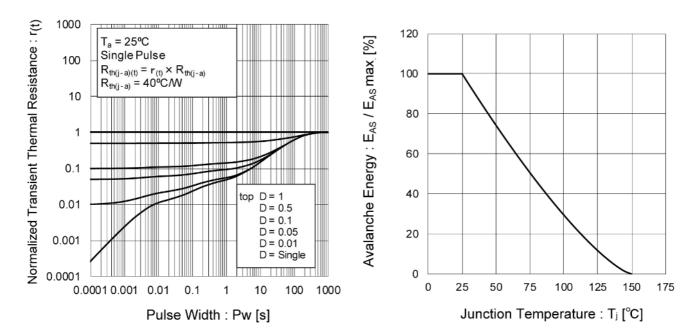


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

Fig.4 Avalanche Energy Derating Curve vs. Junction Temperature



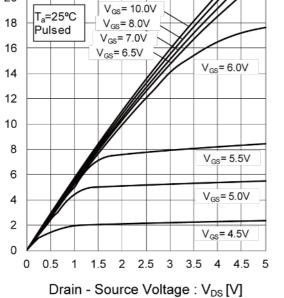




### Fig.5 Typical Output Characteristics(I)

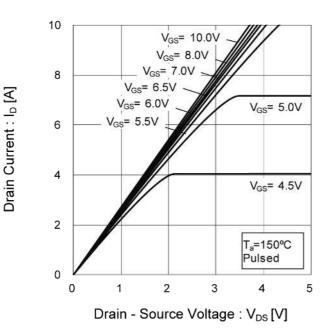
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Drain Current : I<sub>D</sub> [A]

Fig.7 Tj = 150°C Typical Output Characteristics (I)



# Fig.6 Typical Output Characteristics(II)

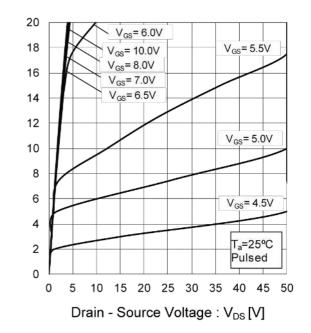
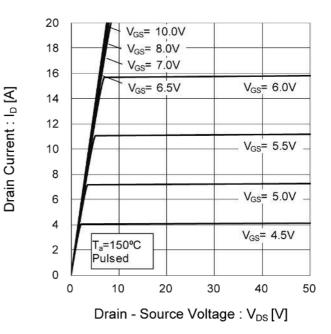
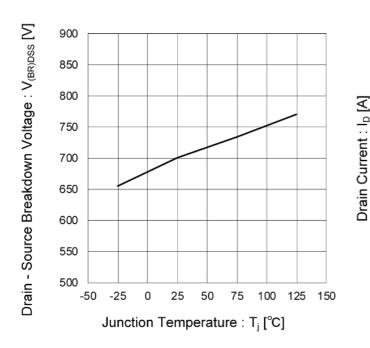


Fig.8 Tj = 150°C Typical Output Characteristics (II)





### Fig.9 Breakdown Voltage vs. Junction Temperature

Fig.10 Typical Transfer Characteristics

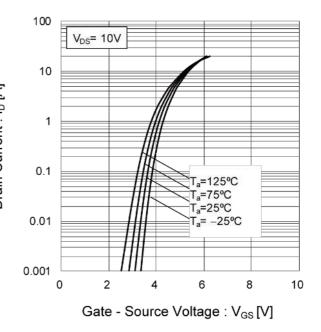
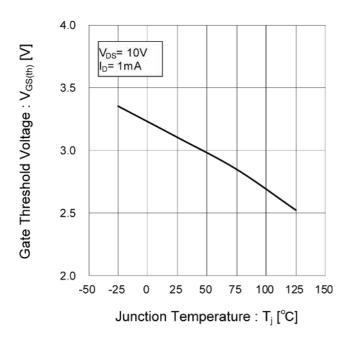


Fig.11 Gate Threshold Voltage vs. Junction Temperature



# Fig.12 Forward Transfer Admittance vs. Drain Current

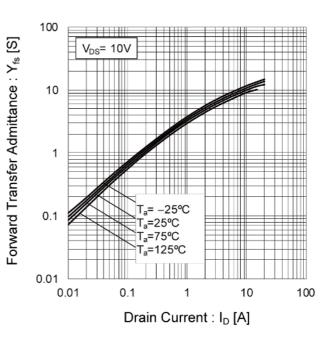


Fig.14 Static Drain - Source On - State

Resistance vs. Junction Temperature

### • Electrical characteristic curves

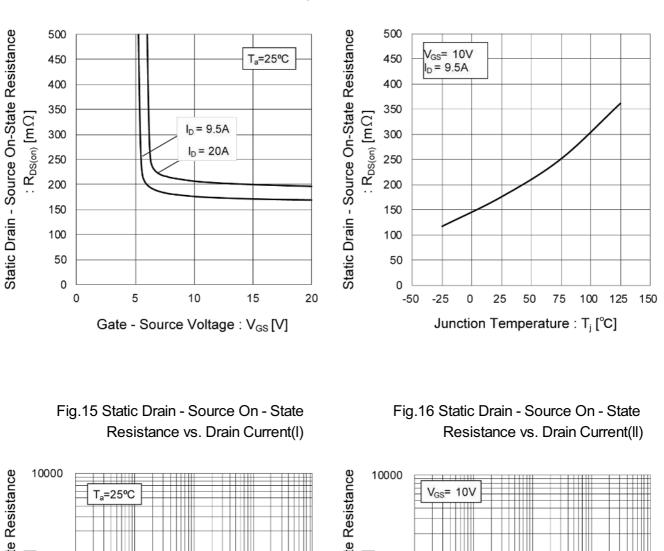
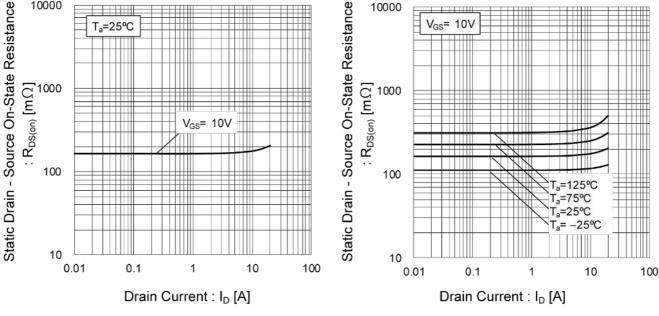
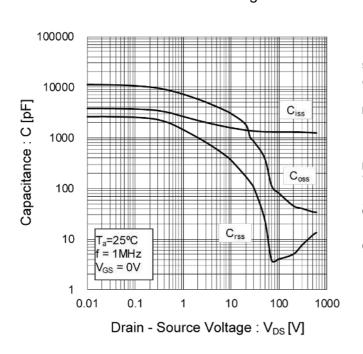


Fig.13 Static Drain - Source On - State Resistance vs. Gate Source Voltage









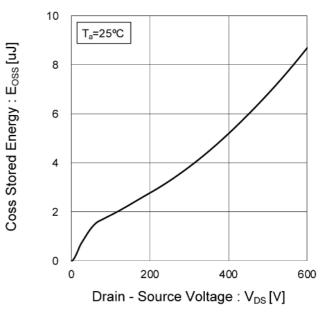
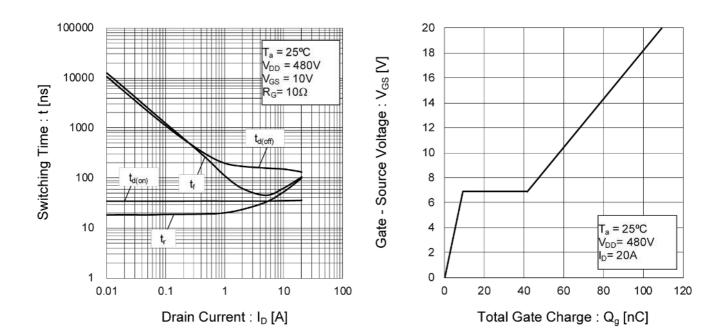
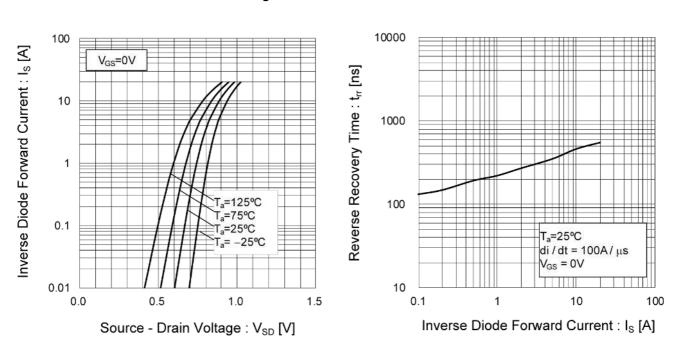


Fig.18 Coss Stored Energy

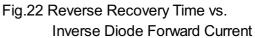
Fig.19 Switching Characteristics

Fig.20 Dynamic Input Characteristics





# Fig.21 Inverse Diode Forward Current vs. Source - Drain Voltage





### Measurement circuits

### Fig.1-1 Switching Time Measurement Circuit

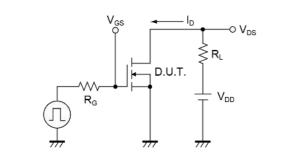


Fig.2-1 Gate Charge Measurement Circuit

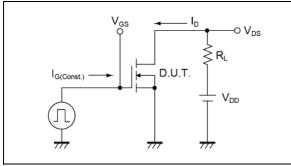


Fig.3-1 Avalanche Measurement Circuit

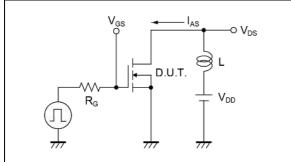


Fig.4-1 dv/dt Measurement Circuit

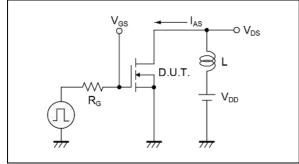
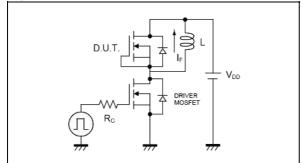
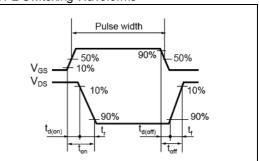


Fig.5-1 dv/dt Measurement Circuit

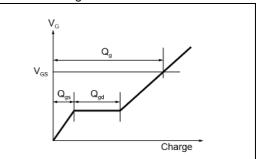


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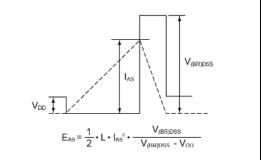
# Fig.1-2 Switching Waveforms



### Fig.2-2 Gate Charge Waveform



### Fig.3-2 Avalanche Waveform



### Fig.4-2 dv/dt Waveform

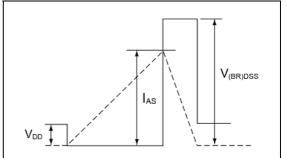
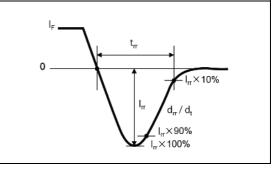
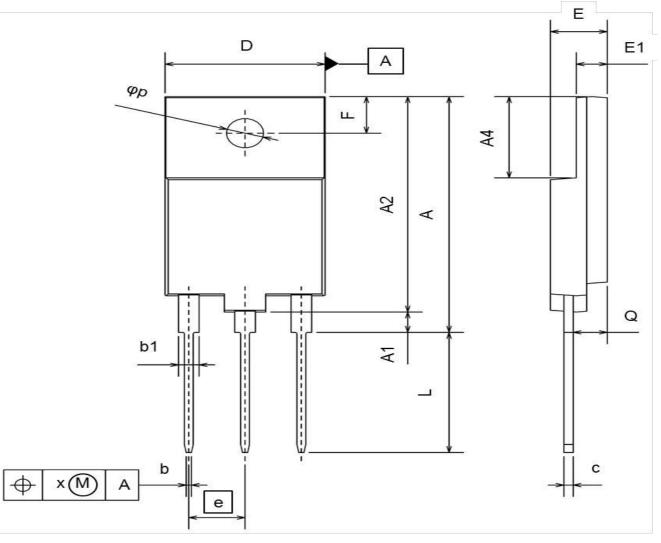


Fig.5-2 dv/dt Waveform





### Dimensions



DIM	MILIME	TERS	INCI	HES
	MIN	MAX	MIN	MAX
A	28.60	29.40	1.126	1.157
A1	2.30	2.70	0.091	0.106
A2	26.30	26.70	1.035	1.051
A4	9.80	10.20	0.386	0.402
b	0.66	0.95	0.026	0.037
b1	1.80	2.20	0.071	0.087
С	0.80	1.00	0.031	0.039
D	15.30	15.70	0.602	0.618
E	5.30	5.70	0.209	0.224
E1	2.80	3.20	0.110	0.126
е	5.4	45	0.2	215
F	4.35	4.65	0.171	0.183
L	14.60	15.00	0.575	0.591
φp	3.40	3.80	0.134	0.150
Q	3.10	3.50	0.122	0.138
Х	-	0.50		0.020

# Dimension in mm / inches

# Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the S	pecific Applications
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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSI	CLASS II b	CLASSII
CLASSⅣ		CLASSⅢ	

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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